# BE EXTC SEE Optical Fibre Comm. Dec 2014

	(3 Hours)	[Total Marks: 100]
N.B.	<ul> <li>(1) Questions No.1 is compulsory.</li> <li>(2) Attempt any four questions from the remaining six questions.</li> <li>(3) Assume suitable data wherever necessary.</li> </ul>	ons.
	<ul><li>(a) Explain three operating windows in optical communication.</li><li>(b) State the difference between the dispersion shifted and dispersion.</li></ul>	5 sion compensated
	fiber.  (c) Compare direct band gap and indirect band gap semiconductor  (d) Derive expression for responsivity of an intrinsic photo detection	$oldsymbol{\smile}$
	quantum efficiency and wavelength.	5
	<ul> <li>(a) A graded index fiber has a core diameter of 45 μm. Core has a p index profile. The fiber has NA of 0.22 and operating at wave Estimate total number of guided mode propagating in the fiber (b) Explain any one fiber fabrication process with neat diagram. different methods of fabrication.</li> </ul>	length of 1.2 µm.
•	<ul><li>(a) Explain all aspects of link power budget and rise time budget.</li><li>(b) What are the factors that are responsible for optical signal attendance dispersion during signal propagation through optical fiber.</li></ul>	10
-	<ul> <li>(a) A silica optical fiber with core diameter large enough to be contheory has a core refractive index of 1.5 and cladding refraction.</li> <li>(i) The critical angle. (ii) The NA. (iii) The acceptant</li> </ul>	ve index 1.47.
	(b) With the help of device structure explain the working of LED at the emphasis on spontaneous and stimulated emission.	and LASER with 10
•	(a) Describe the various methods of splicing individual fibers tog the desirable requirements of good fiber conductor.	
	(b) State the working principle of Raman amplifier and state its ag	pplications. 10
•	(a) Explain basic principle of operation of photo detector. Explain PIN diode and APD as photo detector, also compare their periods.	formance.
	(b) Draw and explain block diagram of Optical receiver along wit sources and relevant equations.	h various noise 10
	<ul> <li>Write short notes on any four:-</li> <li>(a) Optical bandwidth and Electrical bandwidth</li> <li>(b) Coherent and Non coherent optical communication.</li> <li>(c) OTDR.</li> <li>(d) Multiplexing of optical signals.</li> </ul>	20
	(e) Linearly polarized modes.	

## BELEXTCIVIII (Rev) 20/11/2014. Adv. microwave Engg.

QP Code: 15710

	,	(3 Hours)	[ Total Marks :100	
N	.B.: (1) (2) (3) (4)	•	estions.	
1.	(b) J	What is an unilateral figure of merit of an amplifier? What are the causes of low frequency noise and high fiwith the mixer?	requency noise associated	<b>5</b>
	(c) I	Derive the expression of overall noise figure in three case Prove that scattering matrix is symmetrical and recipro	•	5 5
2.	` /	Explain in detail stability criteria for microwave amplification amplification of broadband amplifier design.	ier.	10 10
3.	s-palam S11 = 0 Plot cor	an amplifier to have a gain of 10 dB at 6 GHz using a transfer ( $Z0 = 50\Omega$ ): $0.61 \frac{170^{\circ}}{1.00}$ , S21 = 2.24 $\frac{32^{\circ}}{1.00}$ , S12 = 0 S22 = 0.72 $\frac{1.00}{1.00}$ . Use mater than the stubs.	)	20
4.	S11 = 0 $Fmin =$	s FET has the following S parameter and noise parameter $0.7 - 155^{\circ}$ , $S12 = 0$ , $S21 = 5.0 + 180^{\circ}$ $S22 = 0.51 - 20^{\circ}$ $S23 = 0.45 + 180^{\circ}$ , $S33 = 40$ Design a Low noise a B and power gain of 16dB.		20
5.	S S	A MESFET is biased for Large signal class A operation signal s-parameters at 5GHz. $811 = 0.55 \left[ -150^{\circ} \right]$ , $812 = 0.04 \left[ 20^{\circ} \right]$ $821 = 3.5 \left[ 170^{\circ} \right]$ , $822 = 0.45 \left[ 30^{\circ} \right]$ The large signal $821 = 2.8 \left[ 180^{\circ} \right]$ .  Design a Large signal class A amplifier with max. Transcent		10
	(b) I	Derive the necessary condition for two port NR oscillate	or.	10

- 6. (a) Explain in detail single ended diode mixer. Also explain mixer design aspects.
  (b) Design a transistor oscillator at 4GHz using GaAs FET in common gate configuration with 5nH inductor in series. Common gate configuration s-parameters are S11 = 2.18 [-35°], S21 = 2.75 [96°] S12 = 1.26 [18°], S22 = 0.52 [155°] Select Γ<sub>T</sub> so that Γin >1
- 7. Write short notes on:—

20

- (i) Noise figure test equipment
- (ii) Power amplifier linearity
- (iii) Comparison of microwave amplifier and oscillator.
- (iv) 1dB compression point.

							(3 H	ours)			[	Total N	Marks:	100
			_	estion no.1 is	-	<del>-</del>								
			2. Sol	ve any <b>four</b> fr	om rema	ining.								
		Q.1	(a)	Justify / Cont that represent	-	<b>-</b>	oicture d	lepends	on nun	nber of	pixels a	ınd gray	y levels	05
			(b)	What is K-L	-		is called	as met	hod of t	orincipl	e compo	onents?		05
			(c)	Explain Log t		•			_	· –	ı			05
			(d)	Explain follo	wing meth	od of da	ata comp	oression	indica	ting cle			hey are	05
				(i) Huffman		iato tiro t	ypo or i	o d'un d'un	icy they	, Can III		•		
				(ii) Transform										
				(iii) Adaptive	Delta Mo	dulation				,				
				(iv) Different	ial Pulse c	ode Mod	lulation					-		
				(v) Run lengt	h coding o	n bit pla	nes.							
		0.2	(a)	Explain the m	ethod of s	egmenta	tion of i	mage b	v regioi	n splitti	ng and A	nergina	Y.	10
		<b>~.</b> -	(b)	Draw and exp		•		_		-	<del></del>		<b>J</b>	10
		Q.3	(a)	State and exp	lain the pr	operties	of 2-D F	ourier 1	ransfor	m. (An)	y five)			10
			(b)	Explain with	block diag	gram basi	ic steps f	for filte	ring in	frequen	cy doma	ain.		10
		Q4	(a)	Generate Hu				ing tab	ole in	which	eight	symbo	l with	10
	,		•	Symbol		A1	A2	A3	A4	A5	A	6	A7	
				Probability	<del></del>	0.008	0.022	0.06	0.18		<del></del>		0.48	
			(b)	Obtain Hadar			·	_			ix H(2)	and dra	w flow	10
				diagram for F	1(8). Detin	ie freque	ncy and	mid it	or H(8)	<b>).</b>				
		Q.5	(a)	Histogram of	a digital i	mage wi	th eight	quantiz	ation le	evel is s	hown b	elow. I	erform	10
			( )	histogram equ	<del>-</del>	<del>-</del>	J	•						
				Gray Level	R	0	1	2	3	4	5	6	7	
	•		-	No. of glevel	gray h <sub>r</sub>	220	140	50	60	70	170	130	160	
			(b)	Explain princ	ipal techn	iques to	estimate	e the de	gradati	on fund	ction for	r use in	image	10
ı			` '	restoration.		•			_					
	•	$\alpha$	(0)	Evaloia tha £	Maniera +	achniana	C *							10
		Q.6	(a)	Explain the formation (i)	<del></del> -	etic codi								10
				(i) (ii)		ne Codin	<del></del>							
				<b>\^.</b>			D							

[TURN OVER

2

1	2	3	0	
2	4	6	7	
5	2	4	3	
3	2	6	1	

		(3 Hours) [Total Marks: 100	
N.E	(	<ol> <li>Question No. 1 compulsory.</li> <li>Attempt any four questions out of remaining six questions.</li> <li>Assume suitable data if necessary and state it clearly.</li> </ol>	
1.	(b)	What is TRAP? Explain the significance of TRAP. What are the limitations of SNMP v1? Compare between CMIS/CMIP and SNMP. Describe RMON standard.	
2.	• •	What is ATM remote monitoring ? Describe ADSL configuration management.	10
3.	(a) (b)	Describe different network management models and standards.  What are the functional requirements of NMS Design?	10
4.	(a) (b)	Describe network management tools related to status, route and traffic monitoring.  Explain with neat diagram SNMP v1 PDU format.	10
5.	(a) (b)	Compare between SNMP v1, SNMP v2 and SNMP v3.  Describe the capabilities of RMON2 in Enterprise network management.	10
6.	(a) (b)	Describe the serivices offered by CMISE.  What is policy based security management in SNMP v3?	10
7.	(	te short notes on (any two) :-  (a) SNMP proxy server  (b) TMN conceptual model  (c) Management Information Tree (MIT).	20

## BE EXTC Sess VIII (R)

26/11/14,

Microadure Int. Ckt.

		(3 Hours)	[ Total Marks: 100
N.B	•	) Question No. 1 is compulsory.  2) Answer any four out of remaining six questions	
	`	Answer any rour out of remaining six questions  (a) Assume any suitable data wherever requires.	
	`	Figures to the right indicate marks.	
	(-1	rigules to the right hidred with rist	
1	(a)	Compare microwave integrated circuits with conventional circuits	<b>10</b>
	(b)	Explain construction principle and applications of PIN diode.	10
	(~)		
2.	(a)	Explain green's function and discuss their applications.	10
	(b)	Obtain the dispersion relation for open microstrip.	10
	•		
3.	(a)	Develop wave equation for Coupled lines.	10
	(b)	Explain the concept of narrow band coupled line filter.	10
			40
4.	(a)	Describe a slot line. Explain the waveguide model of analyzing it	
	(b)	Describe all the steps needed to fabricate microstrip resistance.	5
	(c)	Explain briefly ion implantation technique.	5
		To the second of	10
5.	(a)	Explain various configurations of monolithic capacitors.	10 10
	(b)	Discuss the effect of strip thickness on CPW characteristics.	. 10
	(a)	Give the equivalent circuit and working of Varactor diode	. 10
6.	( )	Write short notes on:—	10
	(b)		
		(i) Directional Coupler (ii) Dielectric resonator	

### Sat cossi (Elective)

QP Code: 15781

(3 Hours)

[Total Marks:100

N.B. :	(1) Question Number 1 is Compulsory.	
	(2) Attempt any Four questions from the remaining Six questions.	
	(3) Assume suitable data wherever necessary.	
l. (a)	Explain what is meant by ascending and descending notes. Would you expect them to change with time? Explain.	5
(b)	Explain what is meant by geostationary orbit. How do the this is differ from geosynchronous.	5
(c)	Explain what is meant by "effective path length" in connection with rain attenution.	5
(d)	In most satellite TV receivers the first IF band is converted to a second, fixed IF. Why is this second frequency conversion required?	5
(d)	Explain why the low-noise amplifier of a receivers system is laced at the antenna end of the feeder cable.	5
2. (a)	Explain what is meant by 'noise factor.' For what source temperature is noise factor defined? The EIRP from a satellite is 49.4dBw. Calculate.	2
	(i) The power density at a ground station for which the range is 40,000 km and (ii) The power delivered to a matched load at the ground station receiver if the antenna gain is 50 dB. The downlink frequency is 4GHz.	•
(b)	Explain in detail the operation of the spade system of demand assignment. What is the function of the common signaling channel?	10
3. (a)	Define and explain what is meant by frame efficiency in relation to TDMA operation. Explain why the frame period in a TDMA system is normally chosen to be an integral multiplication of 125 uses.	10
(b)	Explain what is meant by polarization interleaving. With the help of block diagram explain indoor receiving unit of a satellite TV/FM receiving.	10
1. (a)	Why faraday rotation is no concern with circularly polarized waves? Explain how depolarization is caused by rain and ice and it is taken care in link analysis?	10
(b)	Discuss briefly how perturbations affects the planetary motion.	Û
5. (a)	Explain briefly the 'off set feed' used with parabeloidal reflector antenna, stating its main advantaages and disadvantages. Explain with neat diagrams the antennas used in satellite communication.	10
(b)	What are issues fased by communication satellite with respective to life time and reliability? What are space particles? What is their impact on the satellite?	10

6.		Discuss the TT&C system of a communication satellite. Explain what is meant y "redundant receiver" in communication satellite.	1
	(b) D th	Define and explain the term 1-dB compression point. What the significance of his point in relation to the operating point of a TWT? Explain why operation ear the saturation point of a TWTA is to be avoided when multiple carriers are eing amplified.	1
7.	Write	short note (any four):—	. 2
	(a)	Different stabilization techniques.	
	(b)	VSAT	
	(c)	Satellite Radio	

Earth station Design considerations.

(3 Hours)	[ Total Marks: 100

N.	B. :	(1)	Question No. I is compulsory.	
		(2)	Attempt any four questions from remaining Q. Nos. 2 to 7.	
		(3)	Draw neat sketches wherever required.	
		(4)	Assume suitable data if required.	
1.	(a)	Ι	Discuss two evolution paths for the GSM to offer 3G services.	5
	(b)	. [	Discuss briefly HSDPA for WCDMA.	5
	(c)	E	Explain various states in Bluetooth system.	5
	(d)	7	Why is power control used in cdma 2000 and WCDMA?	5
2.	(a)	е	What are the channel types that are used in the UMTS? Discuss the role of each channel type. Also discuss the responsibilities of the RNC and node B in JMTS network?	10
	(b)		What are technical differences between cdma 2000 and WCDMA?	10
3.	(a)		Explain the ZigBee technology? Discuss different types of network topology	10
	( <b>1</b> )		hat are supported in ZigBee.	
	(b)	\	What is WAP? Discuss WAP architecture in brief.	10
4.	(a)	E	Explain IEEE 802.11 WLAN standards. Also discuss WLAN applications.	10
	(b)	7	What is RFID? Discuss some of it's applications.	10
5.	(a)		Discuss WiMax. What are the main differences between the IEEE 802.11b Wi-Fi) and WiMax?	10
	(b)	E	Explain in brief forward and reverse link channels in cdma 2000.	10
6.	(a)	Z	What is imode? What are the major differences between WAP and imode?	10
	(b)	E	Explain B!uetooth security features and security levels with proper diagrams.	10
7.	Ŵrı	ite sh	nort notes on :—	20
	(a	) I	ink budget analysis	
	(b	J = U	Vireless sensor network	